Complementary Power Transistors

DPAK For Surface Mount Applications

Designed for general purpose amplifier and low speed switching applications.

- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("-1" Suffix)
- Lead Formed Version in 16 mm Tape and Reel ("T4" Suffix)
- Electrically Similar to Popular TIP41 and TIP42 Series
- Monolithic Construction With Built-in Base-Emitter Resistors

MJD41C* PNP MJD42C*

*Motorola Preferred Device

SILICON
POWER TRANSISTORS
6 AMPERES
100 VOLTS
20 WATTS

CASE 369A-13 CASE 369-07

RECOMM SURFACE APPLI	I PAD SIZES ENDED FOR E MOUNTED CATIONS
0.243	6.172 1.6 1.6 1.6 1.8 1.8 1.8 1.8 1.8 1.9 1.9 1.9 1.9 1.9 1.9 1.9 1.9

MAXIMUM RATINGS

Rating	Symbol	MJD41C MJD42C	Unit
Collector–Emitter Voltage	VCEO	100	Vdc
Collector–Base Voltage	VCB	100	Vdc
Emitter–Base Voltage	VEB	5	Vdc
Collector Current — Continuous Peak	IC	6 10	Adc
Base Current	ΙΒ	2	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	20 0.16	Watts W/°C
Total Power Dissipation* @ T _A = 25°C Derate above 25°C	PD	1.75 0.014	Watts W/°C
Operating and Storage Junction Temperature Range	T _J , T _{Stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit	
Thermal Resistance, Junction to Case	$R_{\theta JC}$	6.25	°C/W	
Thermal Resistance, Junction to Ambient*	$R_{ heta JA}$	71.4	°C/W	

^{*}These ratings are applicable when surface mounted on the minimum pad size recommended.

Preferred devices are Motorola recommended choices for future use and best overall value.

REV 1

MJD41C MJD42C

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage (1) (I _C = 30 mAdc, I _B = 0)	VCEO(sus)	100	_	Vdc	
Collector Cutoff Current (V _{CE} = 60 Vdc, I _B = 0)	ICEO	_	50	μAdc	
Collector Cutoff Current (V _{CE} = 100 Vdc, V _{EB} = 0)	ICES	_	10	μAdc	
Emitter Cutoff Current (VBE = 5 Vdc, IC = 0)	I _{EBO}	_	0.5	mAdc	
ON CHARACTERISTICS (1)			•		
DC Current Gain (I _C = 0.3 Adc, V_{CE} = 4 Vdc) (I _C = 3 Adc, V_{CE} = 4 Vdc)	hFE	30 15	— 75	_	
Collector–Emitter Saturation Voltage (I _C = 6 Adc, I _B = 600 mAdc)	VCE(sat)	_	1.5	Vdc	
Base–Emitter On Voltage (IC = 6 Adc, VCE = 4 Vdc)	VBE(on)	_	2	Vdc	
DYNAMIC CHARACTERISTICS			•		
Current Gain — Bandwidth Product (2) (I _C = 500 mAdc, V _{CE} = 10 Vdc, f _{test} = 1 MHz)	fT	3	_	MHz	
Small–Signal Current Gain (I _C = 0.5 Adc, V _{CE} = 10 Vdc, f = 1 kHz)	h _{fe}	20	_	_	

⁽¹⁾ Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%. (2) $f_T = |h_{fe}| \cdot f_{test}$.

TYPICAL CHARACTERISTICS

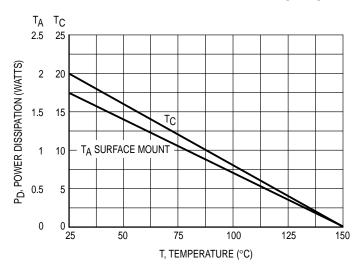


Figure 1. Power Derating

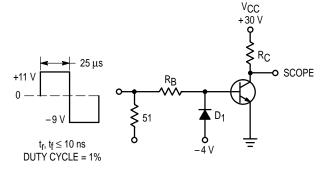


Figure 2. Switching Time Test Circuit

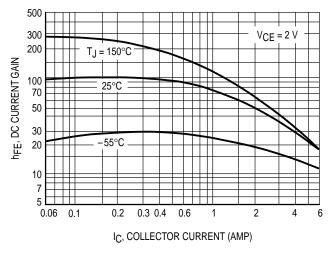


Figure 3. DC Current Gain

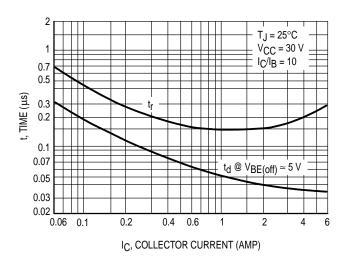


Figure 4. Turn-On Time

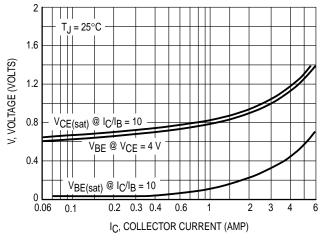


Figure 5. "On" Voltages

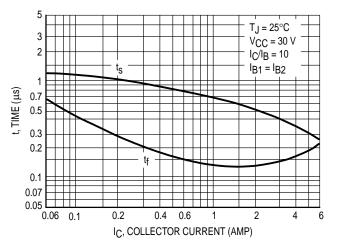
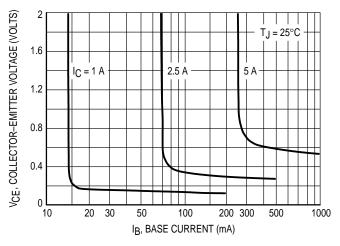


Figure 6. Turn-Off Time

MJD41C MJD42C



300 200 TJ = 25°C TJ = 25°C

Figure 7. Collector Saturation Region

Figure 8. Capacitance

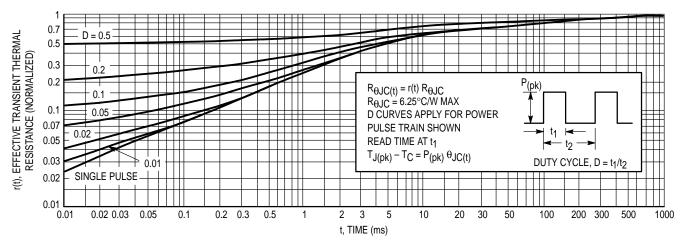


Figure 9. Thermal Response

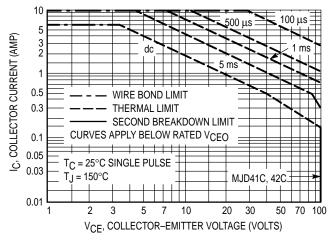
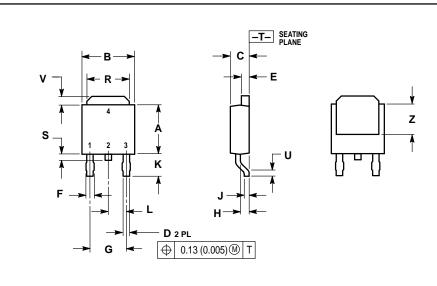


Figure 10. Maximum Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 10 is based on $T_{J(pk)} = 150^{\circ}C$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 9. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

PACKAGE DIMENSIONS

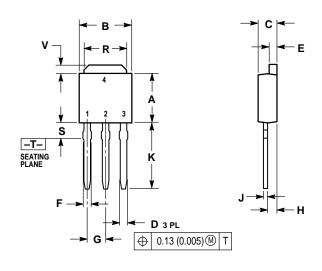


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.250	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
Е	0.033	0.040	0.84	1.01
F	0.037	0.047	0.94	1.19
G	0.180 BSC		4.58 BSC	
Н	0.034	0.040	0.87	1.01
۲	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29	BSC
R	0.175	0.215	4.45	5.46
S	0.020	0.050	0.51	1.27
C	0.020		0.51	
٧	0.030	0.050	0.77	1.27
Z	0.138		3.51	

- STYLE 1:
 PIN 1. BASE
 2. COLLECTOR
 3. EMITTER
 4. COLLECTOR

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NOTES:

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Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.175	0.215	4.45	5.46
S	0.050	0.090	1.27	2.28
٧	0.030	0.050	0.77	1.27

- STYLE 1:
 PIN 1. BASE
 2. COLLECTOR
 3. EMITTER
 4. COLLECTOR

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MJD41C MJD42C

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